

# TECHNICAL DATA

## NPN HIGH POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/408

Devices Qualified Level

2N3715 2N3716

JAN JANTX JANTXV

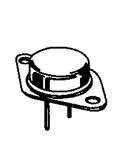
#### MAXIMUM RATINGS

WEIGHT WITH 105				
Ratings	Symbol	2N3715	2N3716	Units
Collector-Emitter Voltage	$V_{CEO}$	60	80	Vdc
Collector-Base Voltage	$V_{CBO}$	80	100	Vdc
Emitter-Base Voltage	$V_{EBO}$	7.0		Vdc
Base Current	$I_{\mathrm{B}}$	4.0		Adc
Collector Current	$I_{C}$	10		Adc
Total Power Dissipation @ $T_A = 25^{\circ}C$	$P_{T}$	5	5.0	W
$@ T_C = 100^{\circ}C$		8	5.7	W
Operating & Storage Junction Temperature Range	T <sub>J.</sub> T <sub>stg</sub>	-65 to +200		$^{0}$ C

### THERMAL CHARACTERISTICS

Characteristics	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	1.17	<sup>0</sup> C/W

<sup>1)</sup> Derate linearly 28.57 mW/ $^{\circ}$ C for T<sub>A</sub> >25 $^{\circ}$ C



TO-3\* (TO-204AA)

\*See Appendix A for Package Outline

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^{\circ}$ C unless otherwise noted)

Characterist	ics	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Current					
$I_C = 10 \text{ mAdc}$	2N3715	$V_{(BR)CEO}$	60		Vdc
	2N3716		80		
Collector-Base Cutoff Current					
$V_{CB} = 80 \text{ Vdc}$	2N3715	$I_{CBO}$		10	μAdc
$V_{CB} = 100 \text{ Vdc}$	2N3716			10	
Emitter-Base Breakdown Voltage					
$V_{EB} = 7.0 \text{ Vdc}$		$I_{\mathrm{EBO}}$		1.0	mAdc
Collector-Emitter Cutoff Current					
$V_{BE} = 1.5 \text{ Vdc}, V_{CE} = 60 \text{ Vdc}$	2N3715	$I_{CEX}$		1.0	mAdc
$V_{BE} = 1.5 \text{ Vdc}, V_{CE} = 80 \text{ Vdc}$	2N3716			1.0	

6 Lake Street, Lawrence, MA 01841

 $1\text{-}800\text{-}446\text{-}1158 \, / \, (978) \, 794\text{-}1666 \, / \, Fax \text{:} \, (978) \, 689\text{-}0803$ 

120101

Page 1 of 2

<sup>2)</sup> Derate linearly  $0.857 \text{ W/}^{\circ}\text{C}$  for  $T_C > 100^{\circ}\text{C}$ 

## **2N3715, 2N3716 JAN SERIES**

## **ELECTRICAL CHARACTERISTICS (con't)**

Characteristics	,	Symbol	Min.	Max.	Unit
Collector-Emitter Cutoff Current					
$V_{CE} = 60 \text{ Vdc}$	2N3715	$I_{CES}$		1.0	mAdc
$V_{CE} = 80 \text{ Vdc}$	2N3716			1.0	
ON CHARACTERISTICS (3)					
Forward-Current Transfer Ratio					
$I_C = 1.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$			50	150	
$I_C = 3.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$		$h_{FE}$	30	120	
$I_C = 5.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$			10		
$I_C = 10$ Adc, $V_{CE} = 4.0$ Vdc			5.0		
Collector-Emitter Saturation Voltage					
$I_C = 5.0 \text{ Adc}, I_B = 0.5 \text{ Adc}$		V <sub>CE(sat)</sub>		1.0	Vdc
$I_C = 10 \text{ Adc}, I_B = 2.0 \text{ Adc}$				2.5	
Base-Emitter Saturation Voltage					
$I_C = 5.0 \text{ Adc}, I_B = 0.5 \text{ Adc}$		$V_{\mathrm{BE}(\mathrm{sat})}$		1.5	
$I_C = 10 \text{ Adc}, I_B = 2.0 \text{ Adc}$				3.0	Vdc
DYNAMIC CHARACTERISTICS				•	
Magnitude of Common Emitter Small-Signal	Short Circuit				
Forward Current Transfer Ratio		$ h_{fe} $	4.0	20	
$I_C = 0.5 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 100 \text{ kHz} -$	1.0 MHz				
Forward Current Transfer Ratio					
$I_C = 0.5 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$		$h_{fe}$	30	300	
Output Capacitance					
$V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$		$C_{obo}$		500	pF

## **SAFE OPERATING AREA**

#### DC Tests

 $T_C = +25^{\circ}C$ , 1 Cycle,  $t \ge 1.0 \text{ s}$ 

### Test 1

 $V_{CE} = 15 \text{ Vdc}, I_C = 10 \text{ Adc}$ 

### Test 2

 $V_{CE} = 40 \text{ Vdc}, I_C = 3.75 \text{ Adc}$ 

#### Test 3

 $V_{CE} = 55 \text{ Vdc}, I_{C} = 0.9 \text{ Adc}$  2N3715  $V_{CE} = 65 \text{ Vdc}, I_{C} = 0.9 \text{ Adc}$  2N3716

(3) Pulse Test: Pulse Width =  $300\mu$ s, Duty Cycle  $\leq 2.0\%$ .

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 794-1666 / Fax: (978) 689-0803

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Microsemi manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H MJ15024/WS MJ15025/WS BC546/116 BC556/FSC BC557/116 BSW67A HN7G01FU-A(T5L,F,T NJVMJD148T4G NSVMMBT6520LT1G NTE187A NTE195A NTE2302 NTE2330 NTE2353 NTE316 IMX9T110 NTE63 NTE65 C4460 SBC846BLT3G 2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA1727TLP 2SA2126-E 2SB1202T-TL-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176 FMC5AT148 2N2369ADCSM 2SB1202S-TL-E 2SC2412KT146S 2SC4618TLN 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E BC557B TTC012(Q) BULD128DT4 JANTX2N3810 Jantx2N5416 US6T6TR KSF350 068071B